

SANYO Semiconductors DATA SHEET



Monolithic Linear IC For Optical Pickups Front Monitor OE-IC

Overview

The LV0220CS is a front monitor optoelectronic IC for optical pickups that has a built-in photo diode compatible with three waveforms. A high-speed process is adopted, and high sensitivity and high reliability are obtained with 405nm AR coating cover glass. Moreover, LV0220CS is small size and thin type CSP packages.

Functions

- I-V amplifier with a built -in PIN type photo detector ($\phi = 0.7$ mm) that supports three wavelengths
- Differential output amplifier
- Mode switching (BD/DVD/CD gain, volume output switching)

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		6	V
Allowable power dissipation	Pd max	Ta ≤ 75°C *	92	mW
Operating temperature	Topr		-10 to +75	°C
Storage temperature	Tstg		-40 to +85	°C

* Mounted on a specified board: 20mm \times 20mm \times 1.6mm, glass epoxy board.

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Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter		Cumbol	Symbol Conditions		Ratings		
		Symbol		min	typ	max	Unit
Operating supply voltage		VCC		4.5	5.0	5.5	V
Operating reference voltage		Vref		1.9	2.2	2.5	V
Mode switch	CD	VswC		2.6		VCC	V
	DVD	VswD	DVD mode when SW pin is floating	1.25	1.65	2.0	V
	BD	VswB		0		0.8	V
Output load capacitance		Co		12	20	33	pF
Output load resistance		Zo		3			kΩ

Electrical and Optical Characteristics at Ta = 25°C, V_{CC} = 5.0V, Vref = 2.2V, R_L = 6k Ω , Rin = 1k Ω

Deservator	Symbol Conditions	Ratings			Unit	
Parameter		Conditions	min	typ	max	Unit
Current dissipation	ICC		9	13	17	mA
Output offset voltage	V _O fs	At shielding, voltage between OUT+ and -	-20	0	+20	mV
Output DC voltage	V _O dc	At shielding, OUT+ and - voltage, Vref standard	-30	0	+30	mV
Temperature dependence of offset voltage *	V _O fsT	Ta = -10 to 85°C, at shielding	20	50	80	μV/°C
Optical output voltage *	V _O C	CD mode, $\lambda = 780$ nm	1.96	2.45	2.94	mV/μW
	V _O D	DVD mode, $\lambda = 650$ nm	2.09	2.61	3.13	mV/μW
	V _O B	BD mode, $\lambda = 405$ nm	0.83	1.04	1.25	mV/μW
D range *	VD	Voltage between OUT+ and -	2200	2600		mV
Frequency characteristics *	f _C C	-3dB (1MHz reference), λ = 780nm	24	30		MHz
	f _C D	-3dB (1MHz reference), $\lambda = 650$ nm	40	50		MHz
	f _C B	-3dB (1MHz reference), λ = 405nm	40	50		MHz
Output noise voltage *	Vn	f = 30MHz, RBW = 30kHz, VBW = 100Hz, Blue mode		-88	-83	dBm
Settling time *	Tset			10		ns
Response time *	Tr, Tf	V_{O} = 0.9Vp-p, output level (10 to 90%), f _C = 10MHz, duty = 50%			15	ns
Response time difference *	ΔTr, Tf	Tr-Tf, $V_O = 0.9Vp-p$, output level (10 to 90%), f _C = 10MHz, duty = 50%	-1.5		+1.5	ns
Overshoot *	Ovst	V _O = 0.9Vp-p			15	%
Undershoot *	Unst	V _O = 0.9Vp-p			15	%
Linearity *	Lin	At output voltages 0.5V and 1.0V	-1		+1	%
Wavelength dependence of output voltage	Vof	$\lambda = 400 \rightarrow 415$ nm	-2		6	%

* : Parameters are design values for reference.

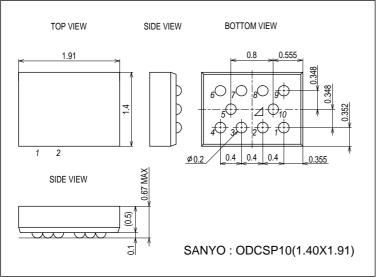
PD-wave length sensitivity ratio (when DVD = 1)

CD	1.1
DVD	1.0
Blue	0.6

Package Dimensions

unit : mm (typ)



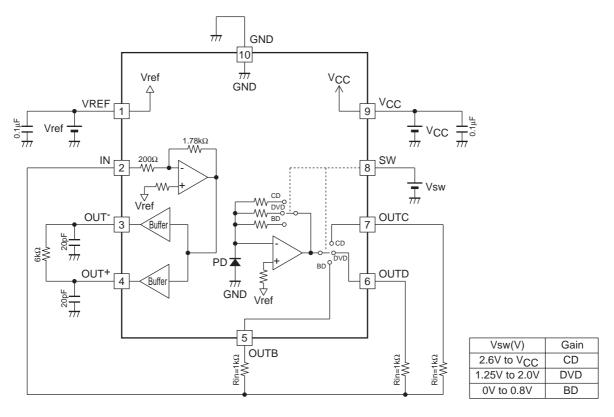


Pin Assignment

OUTD	OUTC	SW	VCC	
6	⑦	(8)	9	
OUTB (5	5)	(10) GND		
(4)	3	2	1	
OUT+	OUT-	IN	VREF	

Bottom view

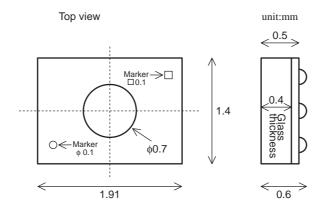
Block Diagram and Test Circuit Diagram



Pin Description						
Pin No.	Pin Name	Description	Equivalent Circuit			
1	VREF	Reference power supply voltage pin.				
2	IN	Differential output input-pin.				
3	OUT- OUT+	Negative side output pin. Positive side output pin.	\uparrow \uparrow			
5	OUTB	Blue mode volume output pin.	\downarrow \checkmark			
6	OUTD	DVD mode volume output pin.				
7	OUTC	CD mode volume output pin.				
8	SW	Mode switch pin.	136kΩ 136kΩ 1kΩ 1kΩ 164kΩ 177 177			
9	V _{CC}	Power supply voltage pin.				
10	GND	Ground pin.				

Photo-receiver Layout

PD aperture size $\phi = 0.7$ mm The center of PD corresponds to the center of the package



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